IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Yoshikazu KASUYA

Application No.:

10/690,025

Filed: October 22, 2003

Docket No.: 117576

For: SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME

MAR 2 2 2004

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

- 1. This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.
- 2. Relevance of reference No. 33 is discussed in the present specification.
- 3. The present application was filed or entered the U.S. National Stage of the PCT after June 30, 2003. In accordance with the June 11, 2003, Notice waiving the requirements of 37 C.F.R. §1.98(a)(2)(i), copies of any U.S. patents and patent application publications are not attached.
- English-language Abstracts of the non-English language references Nos. 30-32 are attached hereto.
- 5. A computer-generated English translation of the following Japanese Patent Publication has been obtained from the website of the Japanese Patent Office ([http://www.jpo.go.jp]), and is attached, but has not been reviewed for accuracy. See References 30-32.

Respectfully submitted,

Registration No. 27,075

Joel S. Armstrong Registration No. 36,430

JAO:JSA/emt

Date: March 22, 2004

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Sheet 1	of	2	
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US Dept. of Commerce PATENT & TRADEMARK OFFICE

ATTY DOCKET NO. 117576

APPLICATION NO. 10/690,025

INFORMATION DISCLOSURE STATEMENT

(Use several sheets if necessary)

APPLICANT Yoshikazu KASUYA

FILING DATE October 22, 2003

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Date: March 22, 2004

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EXAMINER			· · · · · · · · · · · · · · · · · · ·		DATE CONSIDE	RED			
Examiner:	Initial if conforma	citation considered, whether or not ci nce and not considered. Include copy of	tation is in conf	formance with M.P.E.P.	609; draw line thre	ough citation	on if not in		

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